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SEMICONDUCTOR PHYSICS

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M. Ashry and S. Fares
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Wang Wei, Wang Jing, Zhao Mei, Liang Renrong, and Xu Jun

SEMICONDUCTOR MATERIALS

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Zhang Dongyan, Zheng Xinhe, Li Xuefei, Wu Yuanyuan, Wang Jianfeng, and Yang Hui
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Wang Xinjian, Song Hang, Li Zhiming, Jiang Hong, Li Dabing, Miao Guoqing, Chen Yiren, and Sun Xiaojuan

SEMICONDUCTOR DEVICES

- 104001 **An InP-based heterodimensional Schottky diode for terahertz detection (4 pages)**
Wen Ruming, Sun Hao, Teng Teng, Li Lingyun, and Sun Xiaowei
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Li Panpan, Li Hongjian, Zhang Yiyun, Li Zhicong, Liang Meng, Li Jing, and Wang Guohong
- 104003 **High voltage SOI LDMOS with a compound buried layer (5 pages)**
Luo Xiaorong, Hu Gangyi, Zhou Kun, Jiang Yongheng, Wang Pei, Wang Qi, Luo Yinchun, Zhang Bo, and Li Zhaoji
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Hao Daoxin, Cheng Jia, Ji Linhong, and Sun Yuchun
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Du Chunhui, He Changde, Yu Jiaqi, Ge Xiaoyang, Zhang Yongping, and Zhang Wendong
- 104006 **Contact size scaling of a W-contact phase-change memory cell based on numerical simulation (5 pages)**
Wei Yiqun, Lin Xinnan, Jia Yuchao, Cui Xiaole, Zhang Xing, and Song Zhitang
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Wang Yuhai, Qin Zhengkun, Wang Chunxu, and Wang Lizhong

(Continued on inside back cover)

SEMICONDUCTOR INTEGRATED CIRCUITS

- 105001 A low power 2.5–5 GHz low-noise amplifier using 0.5- μ m GaAs pHEMT technology (4 pages)
Peng Yangyang, Lu Kejie, and Sui Wenquan
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Jiang Peichen, Guan Rui, Wang Wufeng, Chen Dongpo, and Zhou Jianjun
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Zhang Qiang, Ni Weining, Shi Yin, and Yu Yude
- 105004 A 1.4-V 48- μ W current-mode front-end circuit for analog hearing aids with frequency compensation (8 pages)
Wang Xiaoyu, Yang Haigang, Li Fanyang, Yin Tao, and Liu Fei
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Zhang Meng and Li Zhiqun
- 105006 A 7–27 GHz DSCL divide-by-2 frequency divider (5 pages)
Guo Ting, Li Zhiqun, Li Qin, and Wang Zhigong
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Han Benguang, Guo Zhongjie, Wu Longsheng, and Liu Youbao
- 105008 A wideband LC-VCO with small VCO gain variation and adaptive power control (6 pages)
Li Bin, Fan Xiangning, and Wang Zhigong
- 105009 Design and optimization of a 0.5 V CMOS LNA for 2.4-GHz WSN application (7 pages)
Chen Liang and Li Zhiqun
- 105010 A 14-bit 200-MS/s time-interleaved ADC with sample-time error calibration (6 pages)
Zhang Yiwen, Chen Chixiao, Yu Bei, Ye Fan, and Ren Junyan
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Li Yanming, Mao Xiangyu, Wen Changbao, and Wen Limin
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Zhao Huidong, Hei Yong, Qiao Shushan, and Ye Tianchun

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Zhao Jianyi, Guo Jian, Huang Xiaodong, Zhou Ning, and Liu Wen
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Wang Zhihao, Liu Wen, Wang Lei, Zuo Qiang, and Zhao Yanli
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Su Jianxiu, Du Jiaxi, Ma Lijie, Zhang Zhuqing, and Kang Renke